

Compact, lightweight and cost-effective high-voltage motor control inverter with GaN

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**Bodo's
Wide Bandgap
Event 2025**

Making WBG Designs Happen

GaN

1 GaN in a Motor Inverter: Washing Machine Use Case

2 Application Test Results

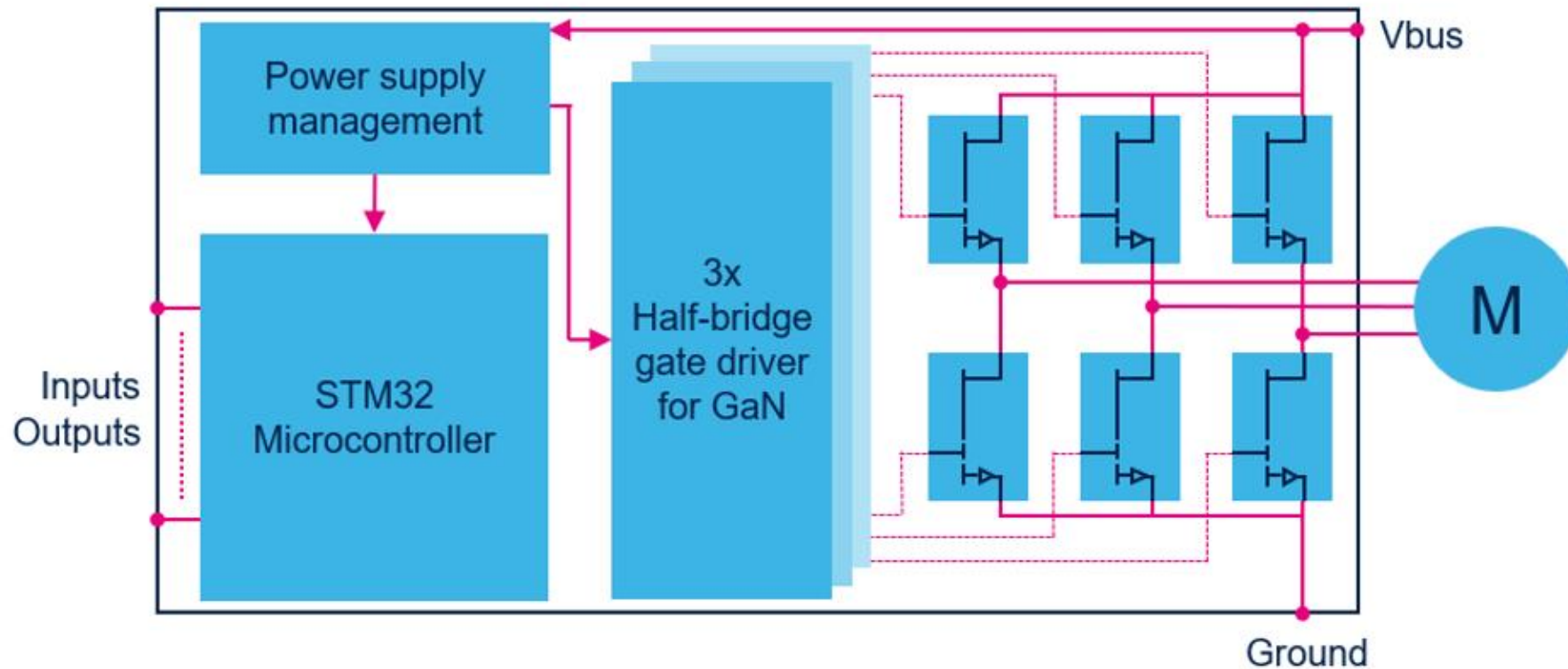
3 Tips and Tricks to Maximize Efficiency

4 Conclusions

GaN in a Motor Inverter: Washing Machine Use Case

Motor Control Power Inverter with GaN

Simplified Block Diagram





Activity details

- Based on **PowerFLAT 8x8 mm** PowerGaNs + GaN Drivers
- Complete Inverter including power supply and EMI filter, designed on a **2-layer PCB, 35µm Cu Thickness**
- **Operates with passive cooling only, without a heatsink**
- Compatible with the latest ST FOC feature: high sensitivity observer, for very low speed operation in sensorless mode



SGT080R70ILB PowerGaN
700 V, 60 mΩ typ.
PowerFLAT 8x8 mm



STDRIVEG611 GaN Gate Driver
600 V, 350/200 mA sink/source



STM32G431 MCU
170 MHz M4 core,
LQFP48 package

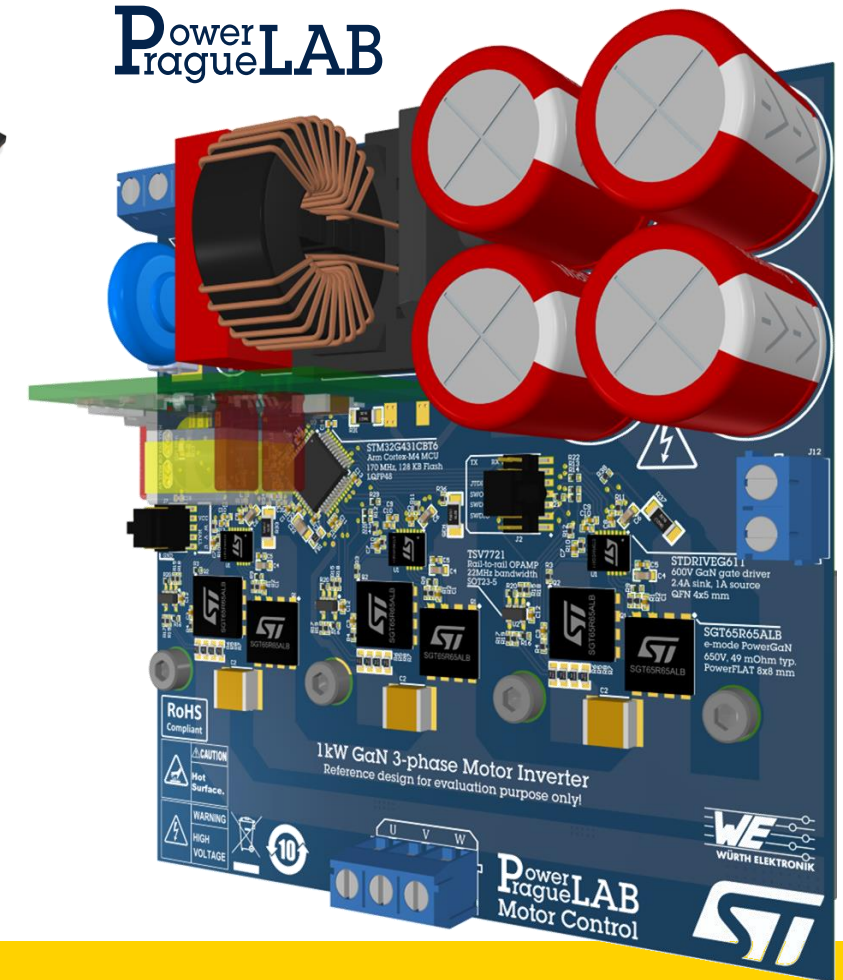


VIPer06 Flyback Controller
800 V, 60 kHz



TSV7721 OpAmps
High bandwidth – 22 MHz
Low offset – 200 µV

Used Inverter 1kW, GaN Based



Test Bench

Washing Machine Motor Use Case

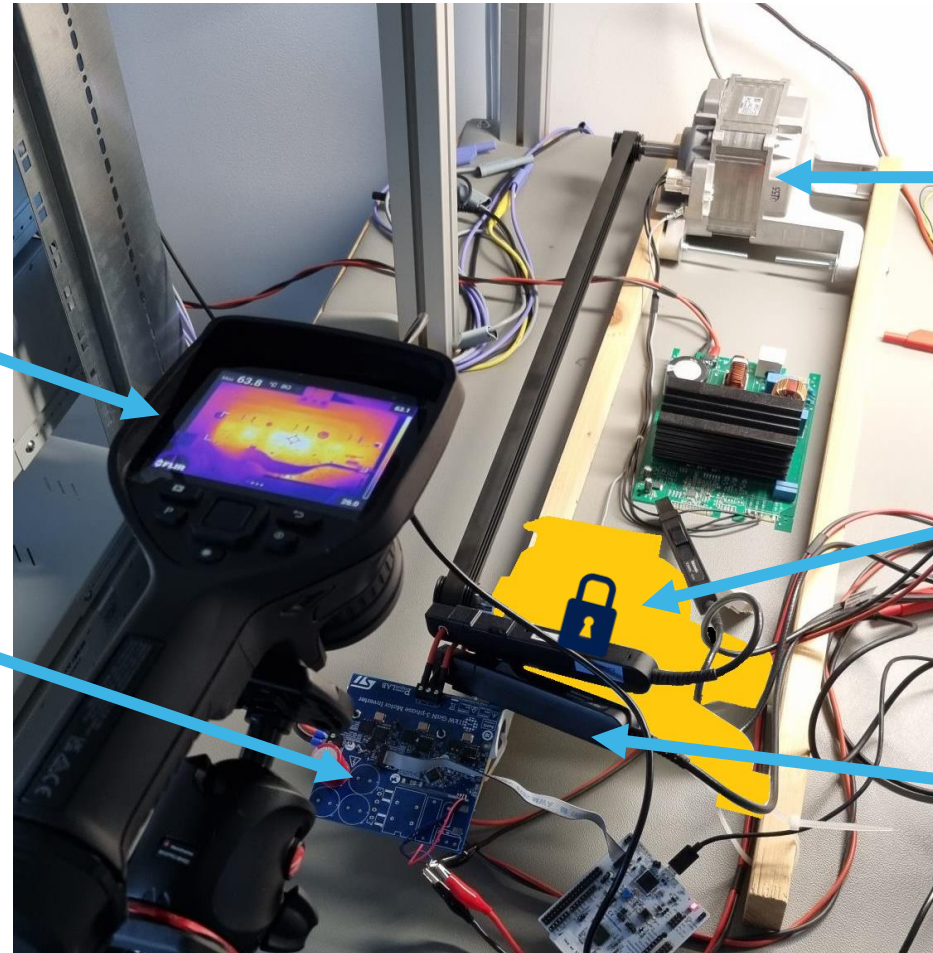
Test bench



- A thermal camera was used to measure temperature without influencing the results
- A **washing machine motor** was connected to another washing machine motor used as a brake, with energy recuperated via a bidirectional power supply
- TCP0030A oscilloscope current probes were used to measure phase current

Thermal camera

GaN Inverter



Load motor
(brake)

Motor
under test

Current
measurement

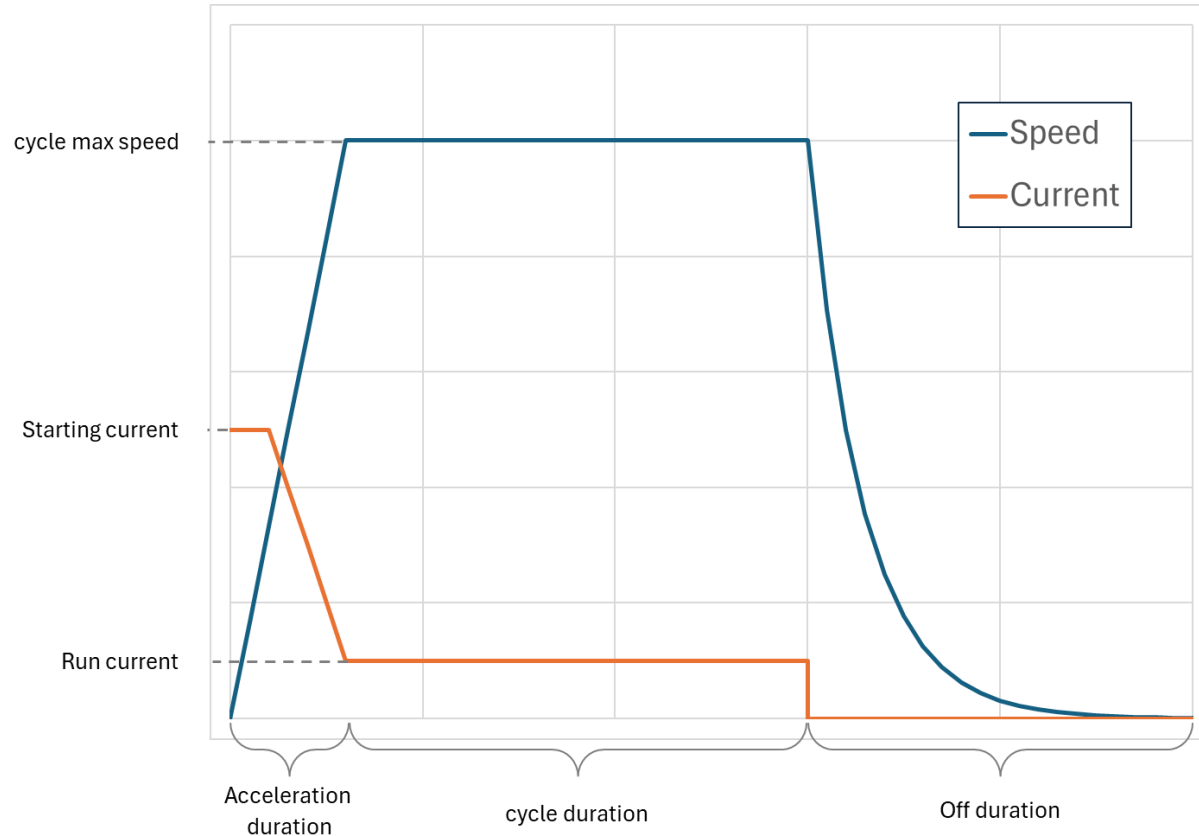
Mission profile

Washing Machine Motor Use Case

- Motor speed was set to 640 RPM (rinse cycle), but this parameter doesn't have big influence on thermal behavior of the inverter

Mission Profile

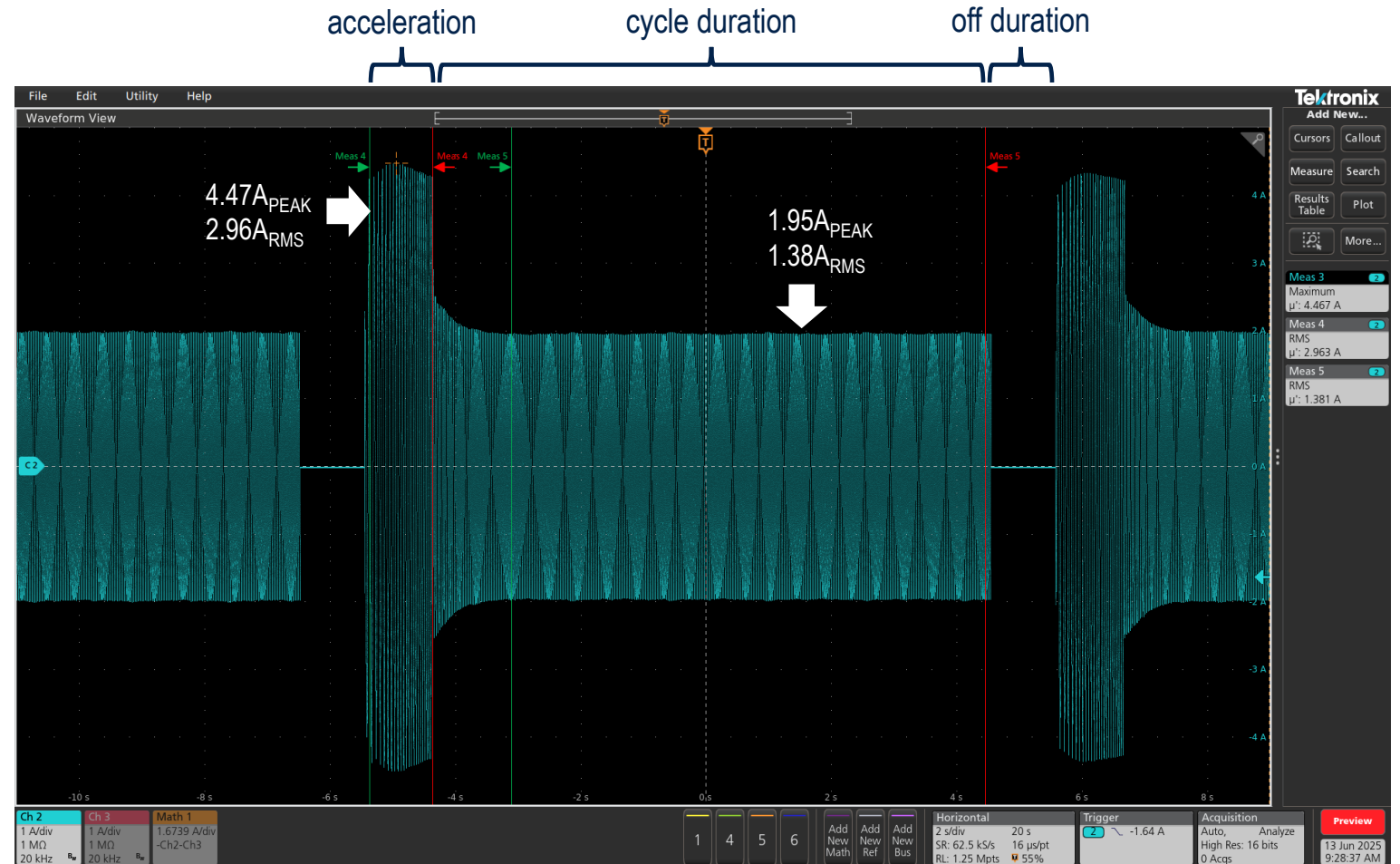
Starting current (A) / (A_{RMS})	4.2 / 2.97
Starting current duration (s)	1.3
Run current (A) / (A_{RMS})	2.0 / 1.41
Cycle max speed (Motor RPM)	640
Acceleration duration (s)	1.13
Cycle duration (s)	10
Off duration (s)	1



- Applied mission profile closely matches requirements
- After each cycle, the motor's rotation direction was reversed
- The defined cycles were continuously repeated for a duration of one hour

Mission Profile

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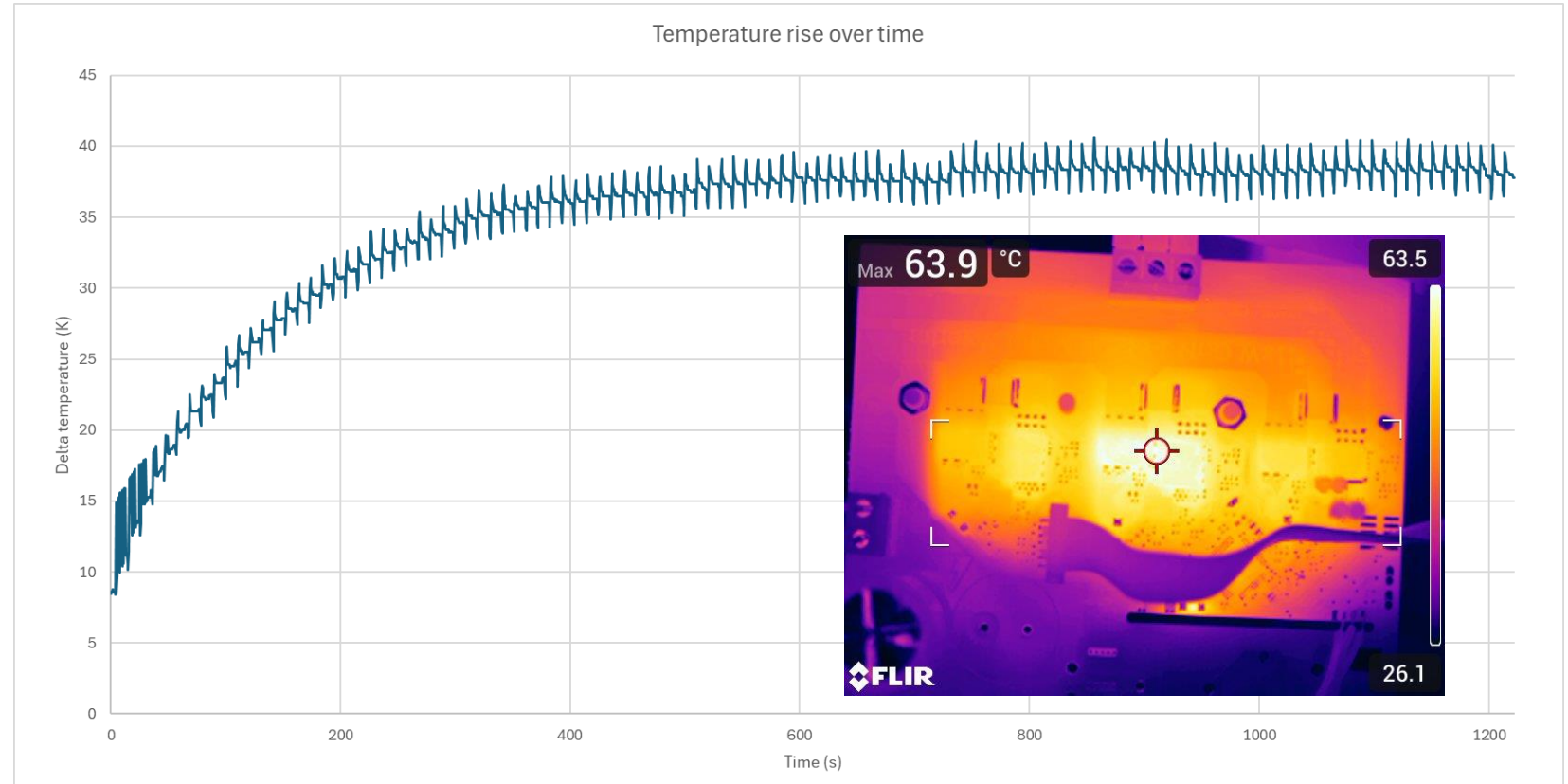
Application Test Results

Temperature measurements

Washing Machine Motor Use Case

Measurement results

- The inverter temperature stabilized after 10 minutes of operation.
- Temperature rise of the transistors was ~40 K in maximum
- Highest transistor temperature was 63,9°C @ 25,7°C ambient
- Temperature was sampled every 0,5 s and a camera effective resolution is 0,2°C.
- Thermal image shows the GaN inverter



2 LAYERS PCB WITH 35μm COPPER LAYERS

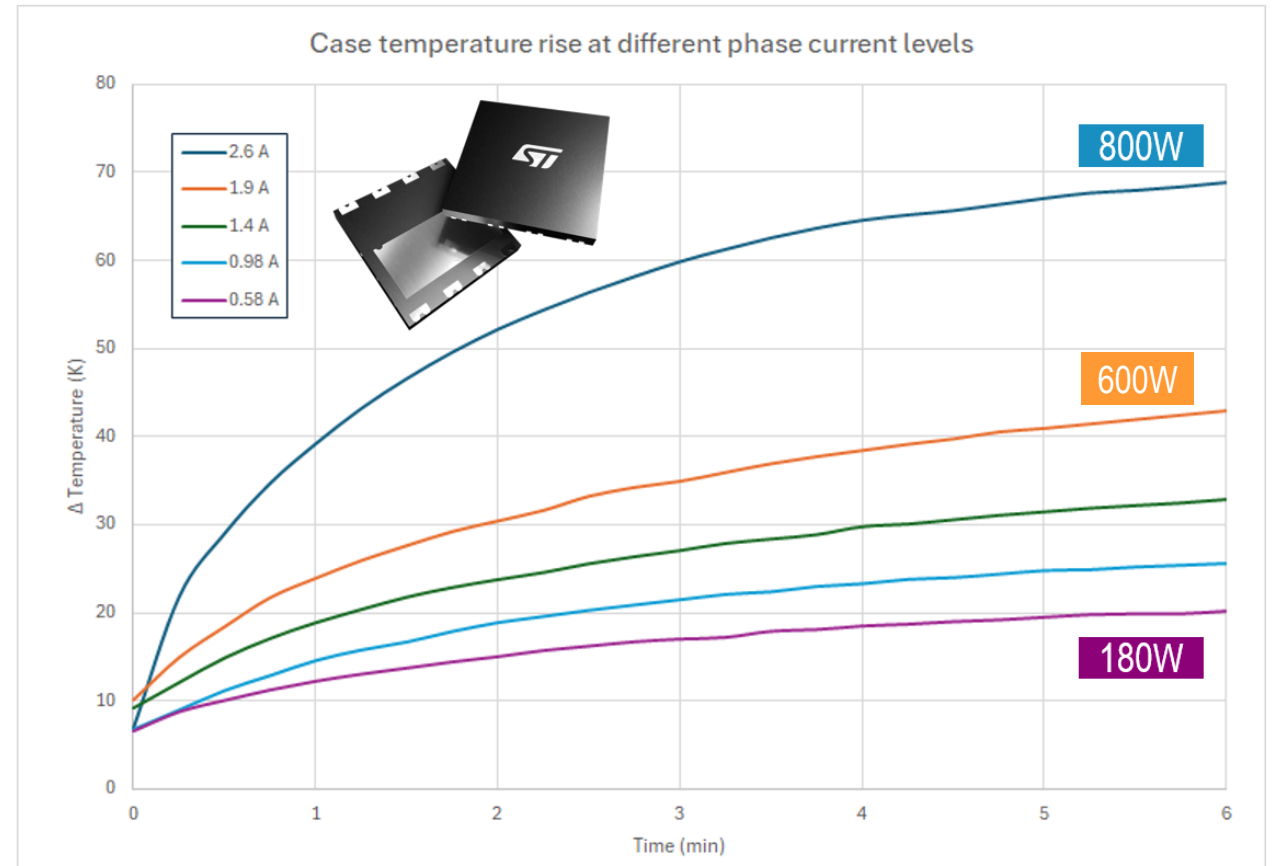
Temperature measurements

Continuous Power

Test Outcome

- Working at 800W brings in $\Delta T < 70^\circ\text{C}$
- The inverter can work up to 600W without any form of heatsink ($\Delta T < 45^\circ\text{C}$)
- In the 200W-400W there is plenty of room to downsize the solution with either higher $R_{\text{DS(on)}}$ transistors (also with integrated solutions)

**HOW TO STRETCH FURTHER THE
NO-HEATSINK SOLUTION AT
HIGHER POWER?**



Tips and Tricks to Maximize Efficiency

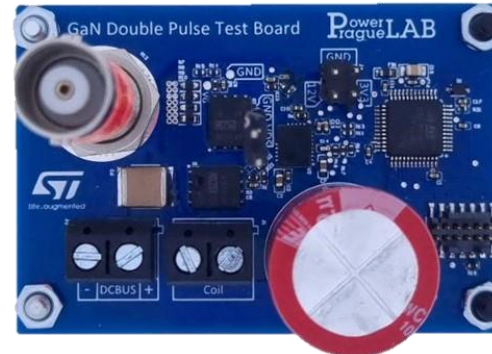
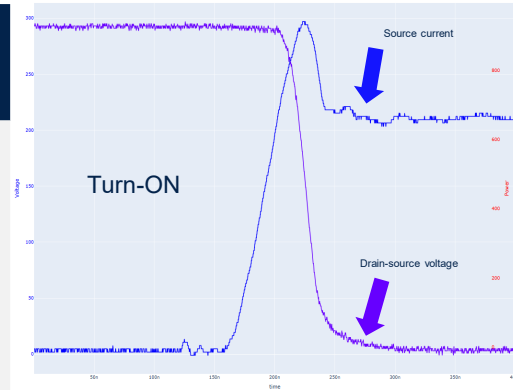
Switching performance

GaN transients in Motor Control

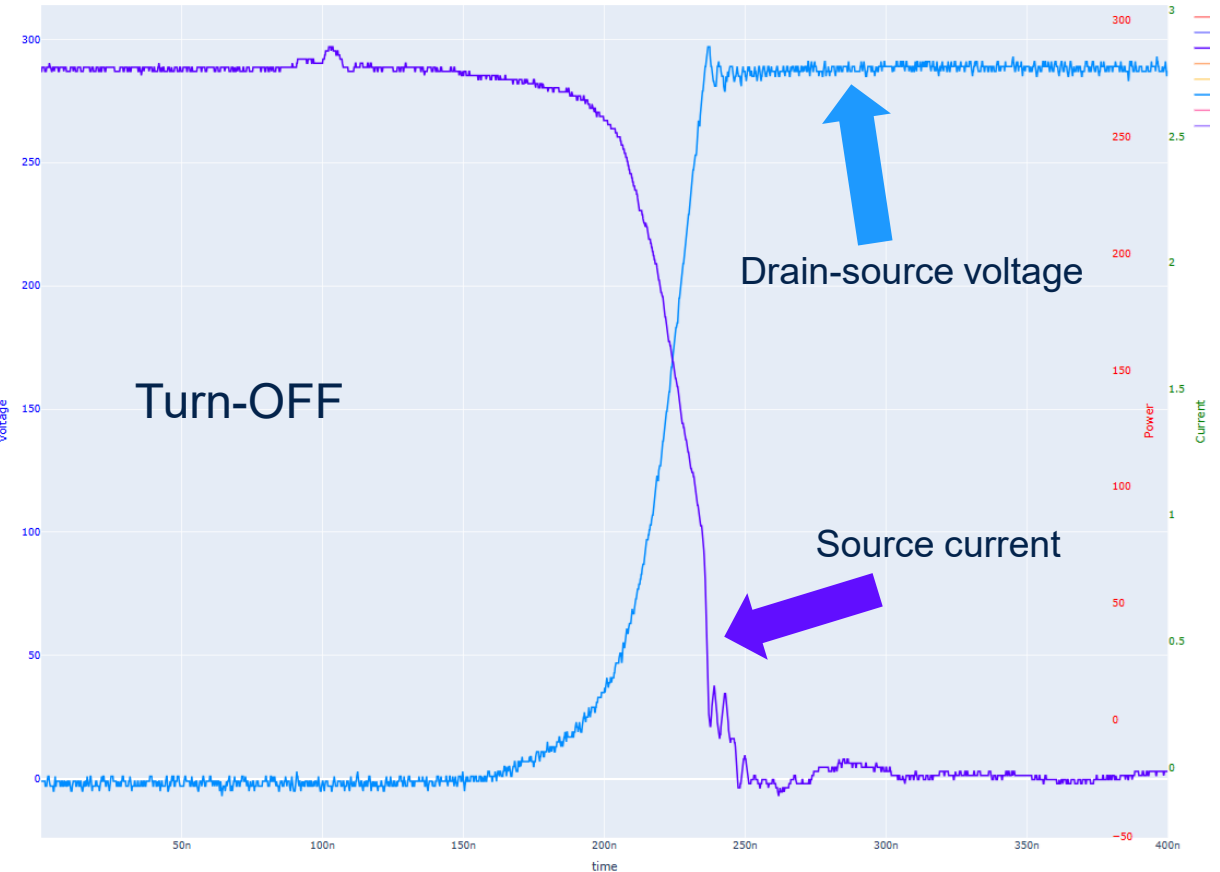
Measurement conclusions



- Switching tuned to 10 V/ns
- Complete switching transient within 100 ns
- Tests performed on real setup with motor
- Switching of the GaN is very clean without major oscillations – beneficial for EMI performance
- Very minor V_{DS} overshoot



Double pulse test platform



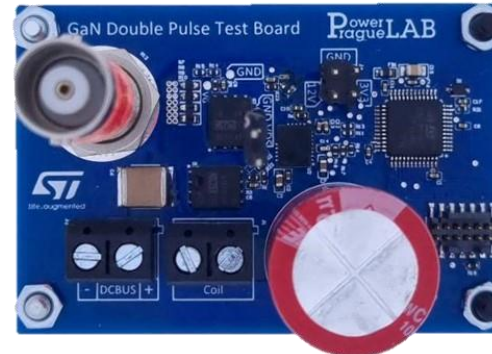
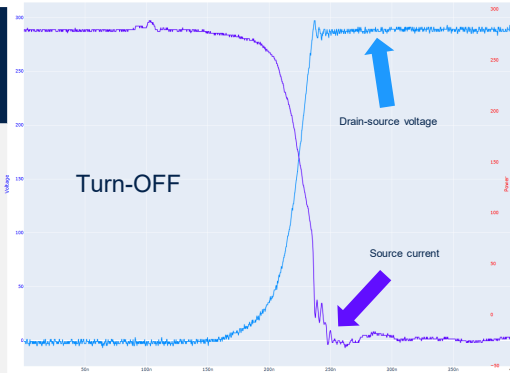
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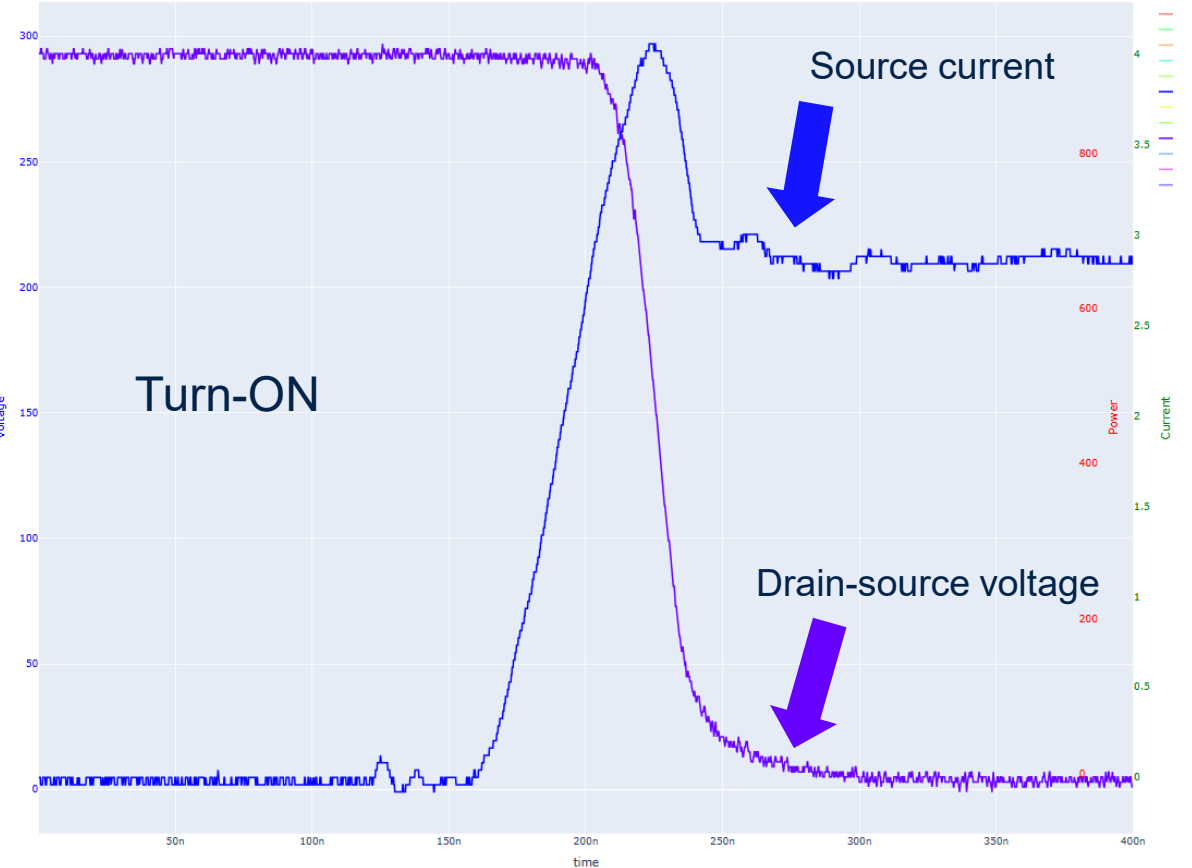
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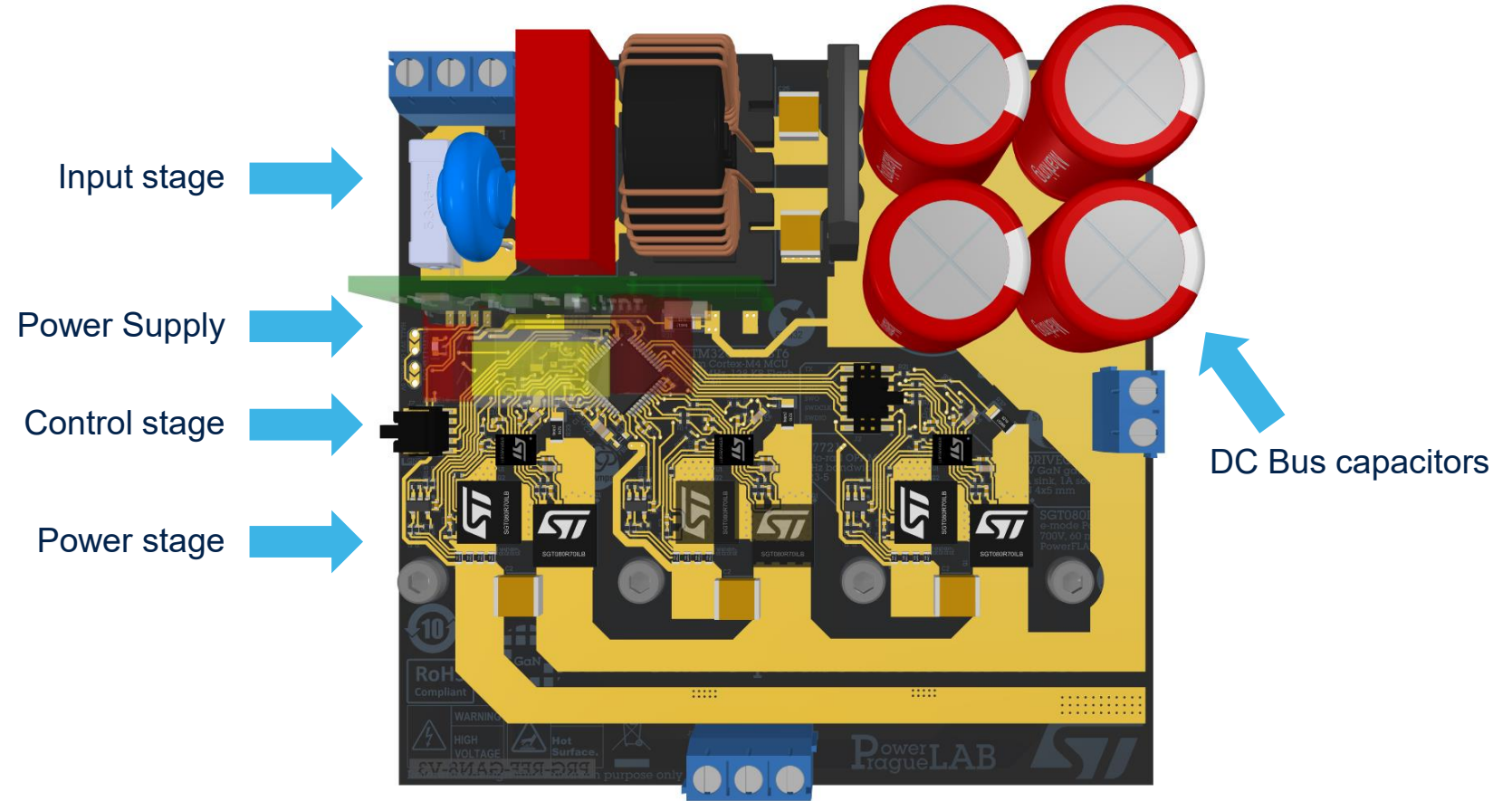
Layout considerations

Minimal current loops

Layout recommendations



- Goal is to have current loops as small as possible in terms of area
- Most important current loops:
 - Main commutation loop
 - Gate current loop
 - DC bus loop
- Important to have good quality ceramic capacitors as a source
- To remove external heatsink, PCB must be able to dissipate all the losses – make the cooling area as big as possible, better with thick plating



Dissipation area size & symmetry → $\Delta T \sim 5C$ estimation

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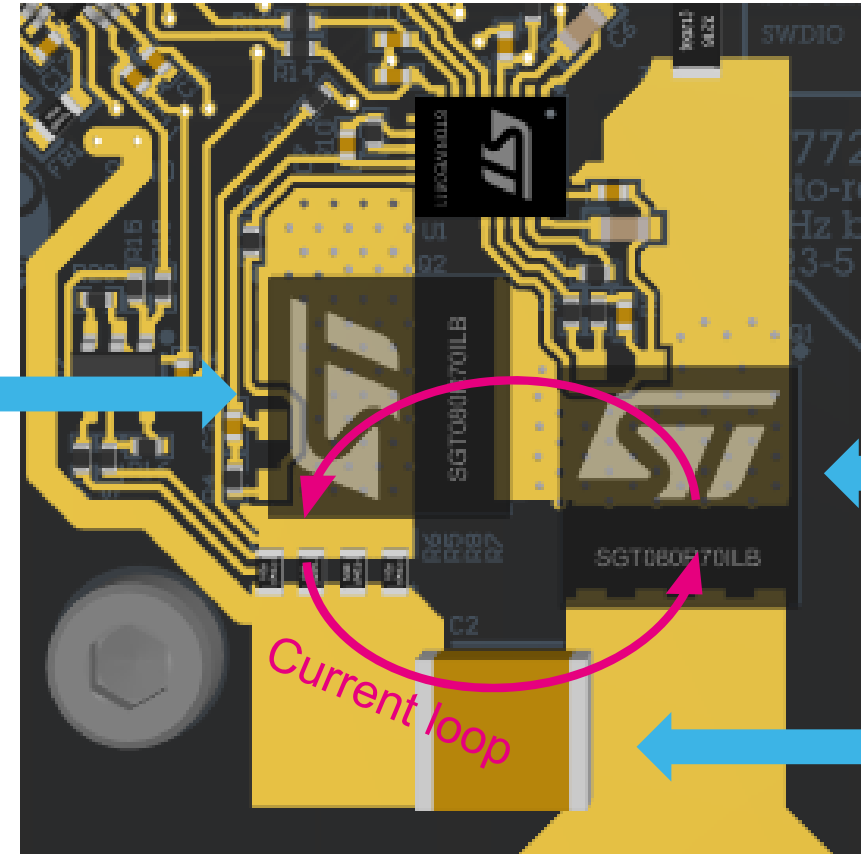
Low side GaN



High side GaN



DC bus capacitor



Main commutation loop as small as possible respecting isolation requirements

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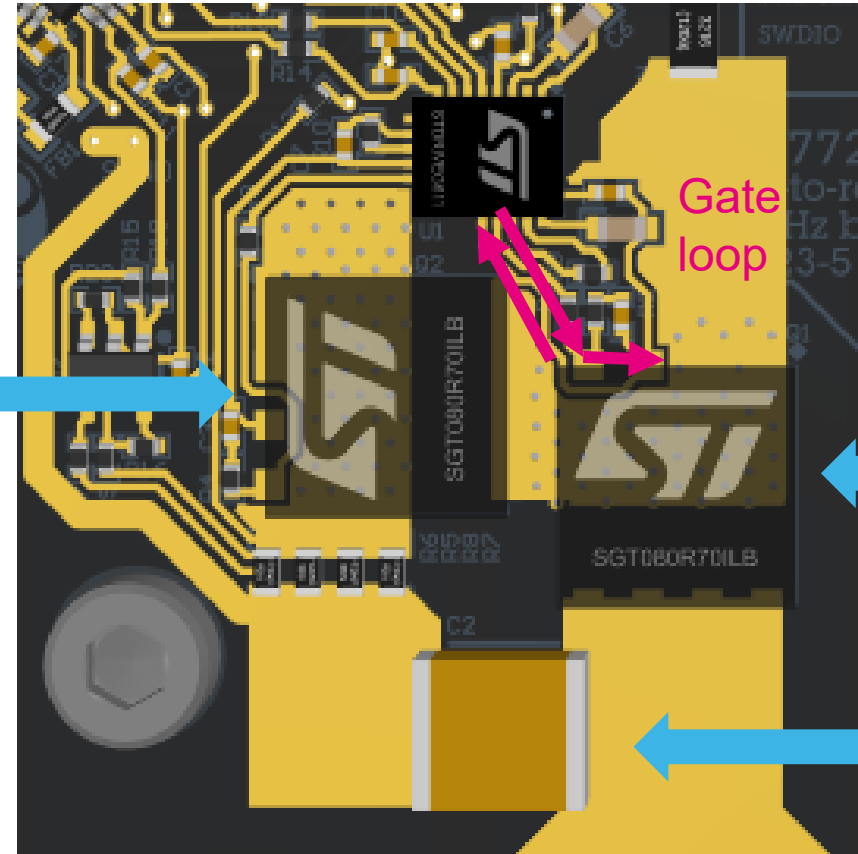
Low side GaN



High side GaN



DC bus capacitor



Gate current supply and return paths are directly next to each other minimizing the area of the loop

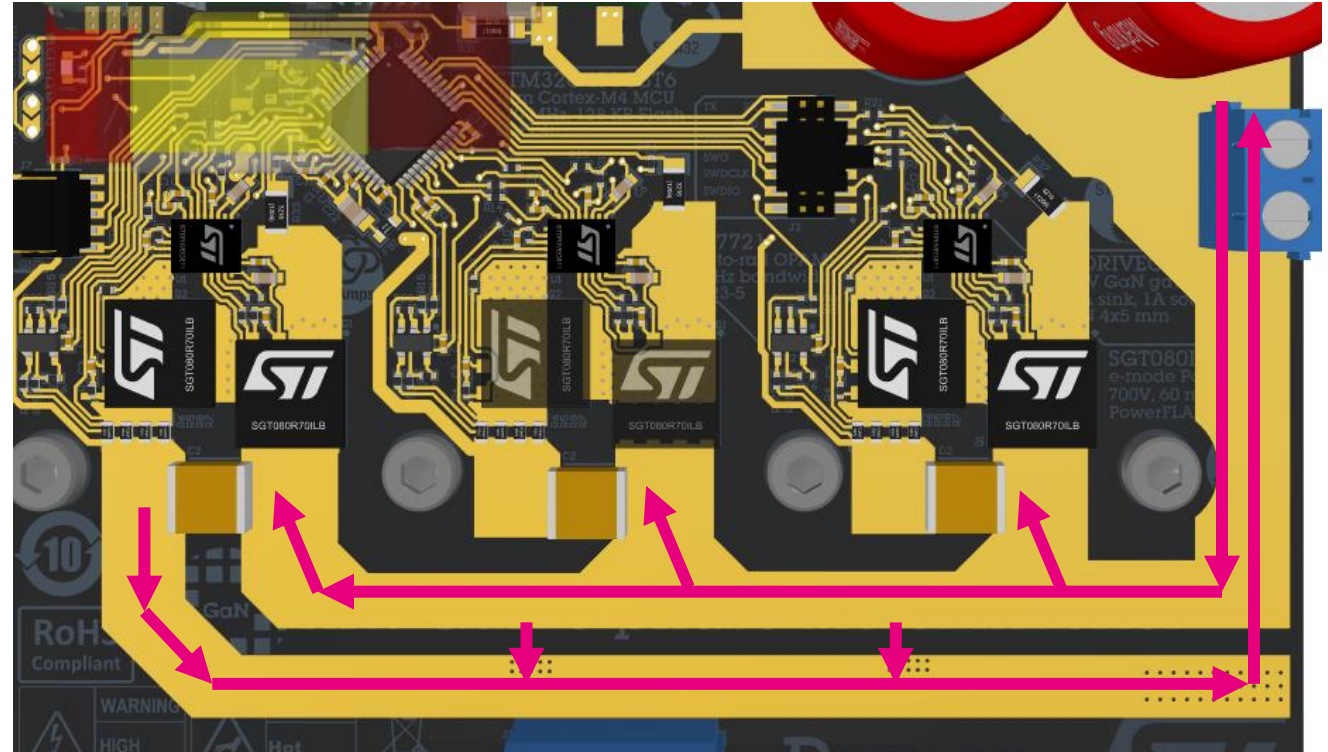
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Considering challenges of 2-layer PCB, area of the DC bus loop is again as small possible

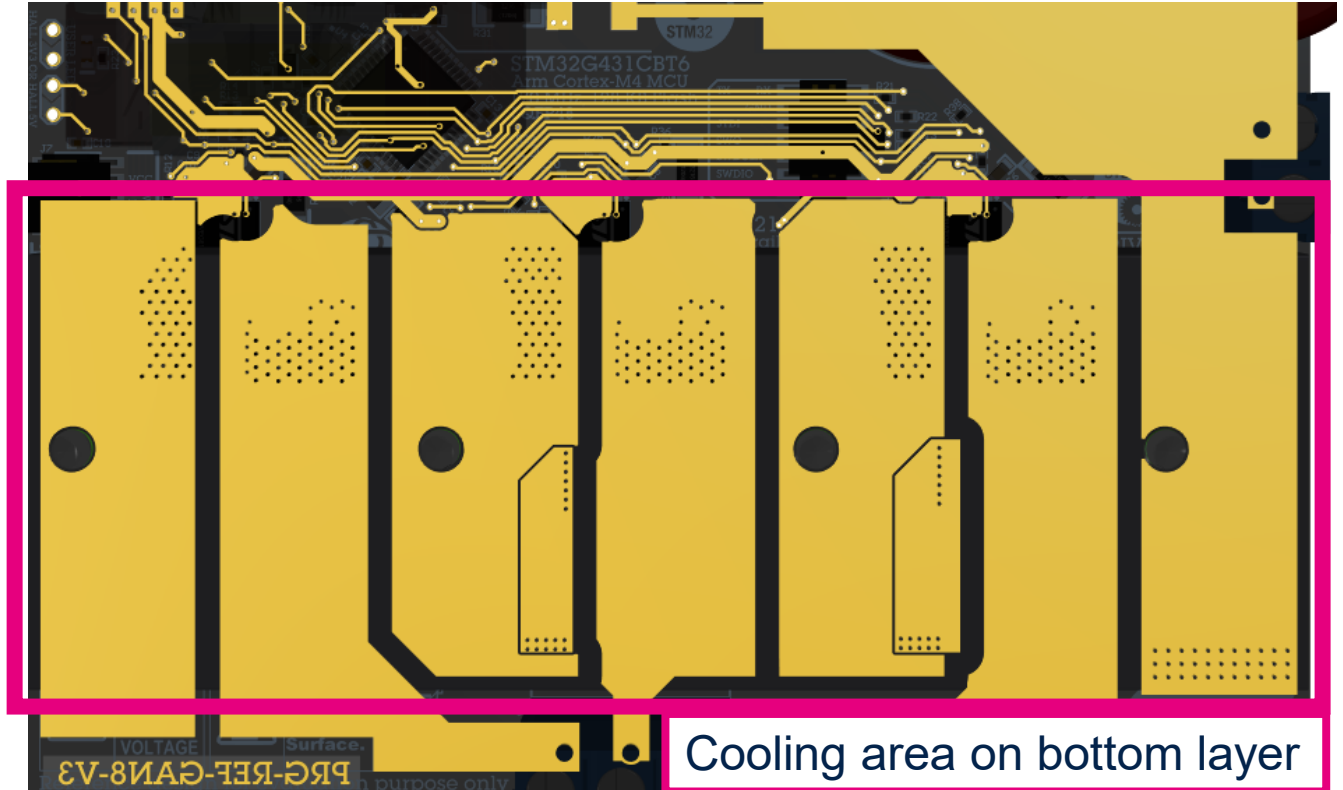
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PCB dissipation area

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Cooling area on bottom layer

Try to keep cooling area as big as possible, consider 70µm plating for demanding applications (gain $\Delta T \sim 15^\circ\text{C}$)

Conclusions

Conclusions

All GaN based solutions bring a significant increase in power density and efficiency in Motor Control getting rid of heatsink and associated cost + manufacturing steps

Layout and PCB constructions are the key design elements for both electrical and thermal performances

Motor cable length strongly influence switching performance: the shorter, the better!

The future for GaN (and SiC): motors with possibility to work at higher dV/dt

Our technology starts with You



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